



DDTC (LO-R1)

NPN PRE-BIASED 100 mA SURFACE MOUNT TRANSISTOR

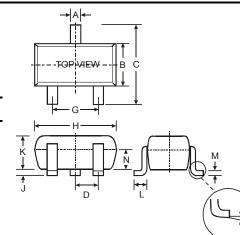
Features

- Epitaxial Planar Die Construction •
- Complementary PNP Types Available (DDTA) •
- **Built-In Biasing Resistors**
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device (Note 3 and 4)

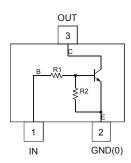
Mechanical Data

- Case: SOT-523 •
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe)
- Terminal Connections: See Diagram
- Marking Information: See Table Below & Page 3
- Ordering Information: See Page 3
- Weight: 0.002 grams (approximate)

P/N	R1 (NOM)	R2 (NOM)	MARKING
DDTC122LE	0.22KΩ	10KΩ	N81
DDTC142JE	0.47KΩ	10KΩ	N82
DDTC122TE	0.22KΩ	OPEN	N83
DDTC142TE	0.47KΩ	OPEN	N84



	SOT-523										
Dim	Min	Max	Тур								
Α	0.15	0.30	0.22								
В	0.75	0.85	0.80								
С	1.45	1.75	1.60								
D			0.50								
G	0.90	1.10	1.00								
н	1.50	1.70	1.60								
J	0.00	0.05									
к	0.60	0.80	0.75								
L	0.10	0.30	0.22								
М	0.10	0.20	0.12								
Ν	0.45	0.65	0.50								
α	0°	8°	_								
	imens	ions in	mm								



Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified

6 0 1				
Characteristic		Symbol	Value	Unit
Supply Voltage, (3) to (2)		V _{CC}	50	V
Input Voltage, (1) to (2)	DDTC122LE DDTC142JE	V _{IN}	-5 to +6 -5 to +6	V
Input Voltage, (2) to (1)	DDTC122TE DDTC142TE	VEBO (MAX)	5	V
Output Current	All	lc	100	mA
Power Dissipation	(Note 1)	Pd	150	mW
Thermal Resistance, Junction to Ambient Air	(Note 1)	$R_{ ext{ heta}JA}$	625	°C/W
Operating and Storage Temperature Range		T_{j}, T_{STG}	-55 to +150	°C

Note: Mounted on FR4 PC Board with recommended pad layout at http://www.diodes.com/datasheets/ap02001.pdf. 1.

2. No purposefully added lead.

3.

Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date 4. Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



Electrical Characteristics @T_A = 25°C unless otherwise specified

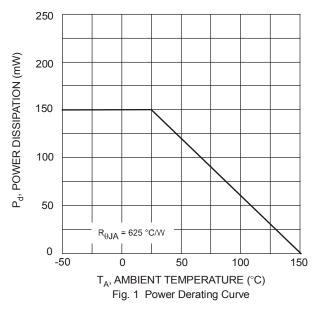
Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition			
	DDTC122LE DDTC142JE	V _{l(off)}	0.3 0.3			V	V _{CC} = 5V, I _O = 100μA		
Input Voltage	DDTC122LE DDTC142JE	V _{l(on)}	_	_	2.0 2.0	V	$V_0 = 0.3V$, $I_0 = 20mA$ $V_0 = 0.3V$, $I_0 = 20mA$		
Output Voltage	V _{O(on)}	_		0.3V	V	I _O /I _I = 5mA/0.25mA			
Input Current DDTC122LE DDTC142JE		I			28 13	mA	V _I = 5V		
Output Current		I _{O(off)}	_	_	0.5	μA	V _{CC} = 50V, V _I = 0V		
DC Current Gain	DDTC122LE DDTC142JE	GI	56 56	_	_	—	V _O = 5V, I _O = 10mA		
Gain-Bandwidth Product*		f⊤	_	200	_	MHz	V _{CE} = 10V, I _E = 5mA, f = 100MHz		

R1, R2 Types

* Transistor - For Reference Only

Electrical Characteristics $@T_A = 25^{\circ}C$ unless otherwise specified R1-Only Types Characteristic Symbol Min Тур Max Unit **Test Condition** Collector-Base Breakdown Voltage 50 V **BV**_{CBO} I_C = 50μA ____ Collector-Emitter Breakdown Voltage 40 V $I_C = 1mA$ **BV**_{CEO} DDTC122TE I_E = 50μA Emitter-Base Breakdown Voltage 5 V $\mathsf{BV}_{\mathsf{EBO}}$ DDTC142TE $I_E = 50 \mu A$ Collector Cutoff Current 0.5 μA $V_{CB} = 50V$ **I**CBO DDTC122TE 0.5 Emitter Cutoff Current $V_{EB} = 4V$ I_{EBO} μA DDTC142TE 0.5 ____ Collector-Emitter Saturation Voltage 0.3 V $V_{\text{CE(sat)}}$ $I_{C} = 5mA$, $I_{B} = 0.25mA$ ____ DDTC122TE 100 250 600 DC Current Transfer Ratio h_{FE} I_{C} = 1mA, V_{CE} = 5V DDTC142TE 100 250 600 Gain-Bandwidth Product* 200 MHz V_{CE} = 10V, I_E = -5mA, f = 100MHz f⊤

* Transistor - For Reference Only



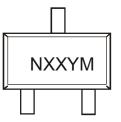


Ordering Information (Note 5)

Device	Packaging	Shipping
DDTC122LE-7-F	SOT-523	3000/Tape & Reel
DDTC142JE-7-F	SOT-523	3000/Tape & Reel
DDTC122TE-7-F	SOT-523	3000/Tape & Reel
DDTC142TE-7-F	SOT-523	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



Nxx = Product Type Marking Code (See Page 1) YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Year	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	Ν	Р	R	S	Т	U	V	W	Х	Y	Z

Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D

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